

PDTD143ET

50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

13 October 2022

Product data sheet

1. General description

NPN Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complement: PDTB143ET

2. Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- ± 10 % resistor ratio tolerance
- High temperature applications up to 175 °C

3. Applications

- IC inputs control
- · Cost-saving alternative to BC807 series transistors in digital applications
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	500	mA
R1	bias resistor 1 (input)		[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	0.9	1	1.1	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	3	
2	GND	ground (emitter)		R1
3	0	output (collector)	SOT23	GND R2

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PDTD143ET	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PDTD143ET	%4Z

[1] % = placeholder for manufacturing site code

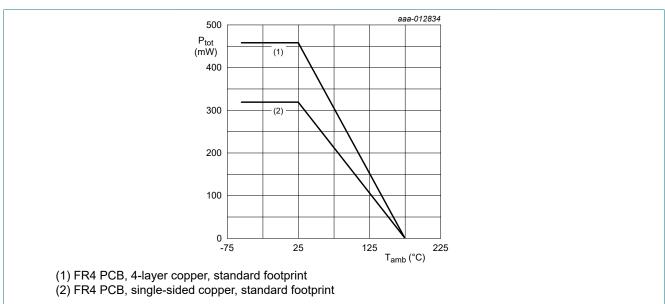
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
VI	input voltage	positive		-10	30	V
Io	output current			-	500	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	320	mW
			[2]	-	460	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-55	175	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



Product data sheet

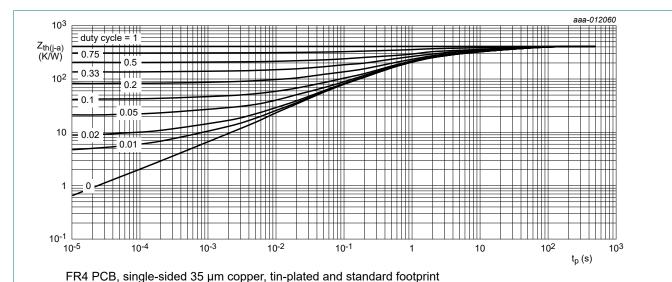
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9. Thermal characteristics

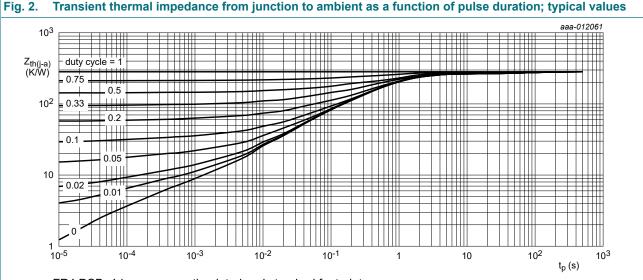
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)		in free air	[1]	-	-	470	K/W
	junction to ambient		[2]	-	-	327	K/W

- Device mounted on an FR4 PCB, 35 μm copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, tin-plated and standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 3.

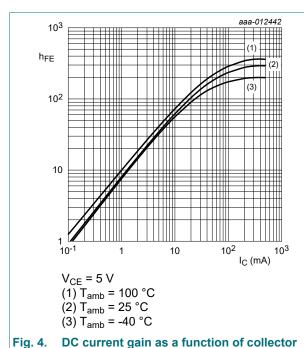
50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

10. Characteristics

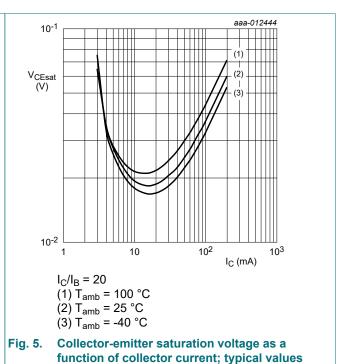
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = 40 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 50 V; I _B = 0 A; T _{amb} = 25 °C		-	-	0.5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	0.9	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 50 mA; T _{amb} = 25 °C		60	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	mV
$V_{I(off)}$	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		0.6	0.9	1.5	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 20 mA; T _{amb} = 25 °C		1	1.6	2.2	V
R1	bias resistor 1 (input)		[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	0.9	1	1.1	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_{E} = 0 \text{ A}; i_{e} = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	7	-	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 50 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	225	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.



current; typical values



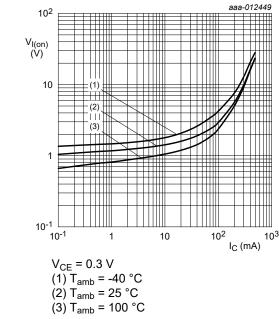


Fig. 6. On-state input voltage as a function of collector | Fig. 7. current; typical values

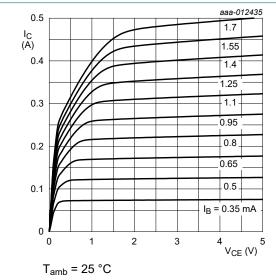
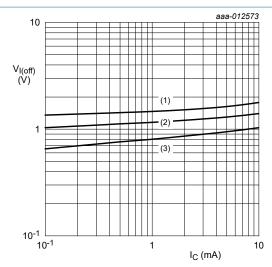
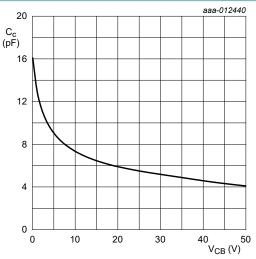


Fig. 8. Collector current as a function of collectoremitter voltage; typical values



V_{CE} = 5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

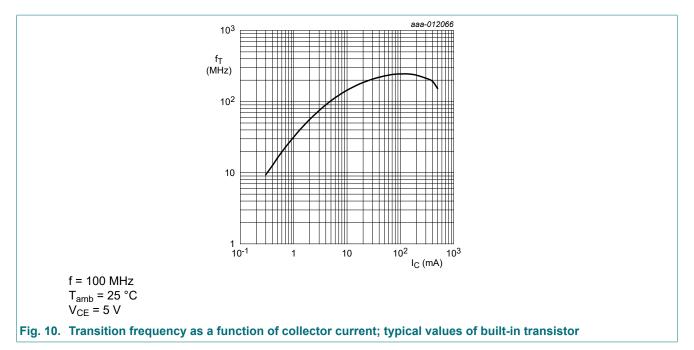
Off-state input voltage as a function of collector current; typical values



f = 1 MHzT_{amb} = 25 °C

Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values

50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω



50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

11. Test information

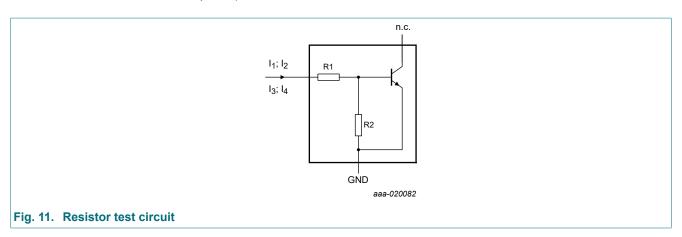
Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



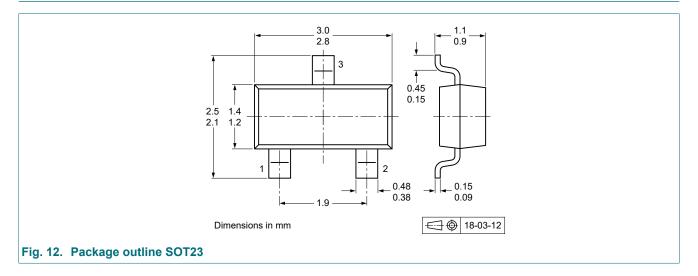
Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PDTD143ET	4.7	4.7	1.3 mA	1.5 mA	-1.05 mA	-1.25 mA

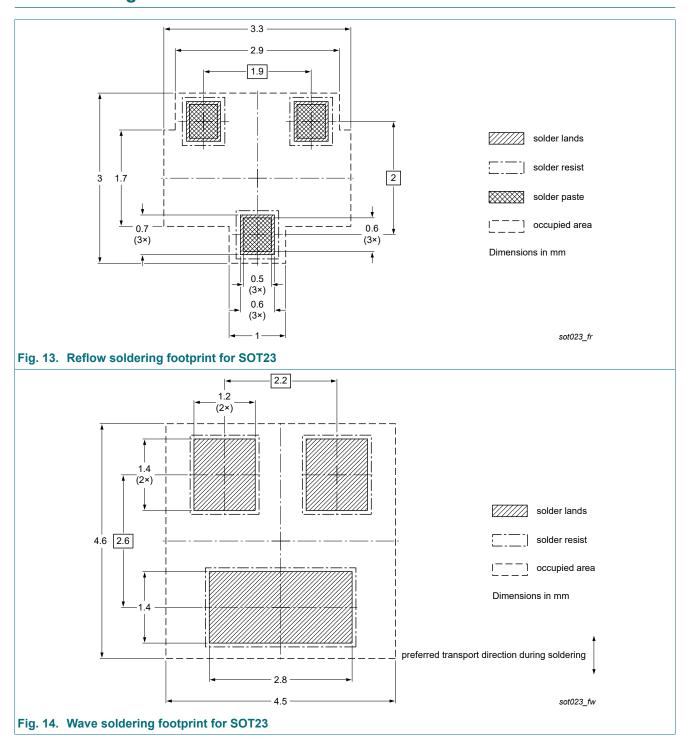
50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

12. Package outline



50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

13. Soldering



50 V, 500 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PDTD143ET v.2	20221013	Product data sheet	-	PDTD1XXXT_SER v.1		
Modifications:	 Family data sheet reduced to single type data sheet. Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). 					
PDTD1XXXT_SER v.1	20140515	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	. Characteristics	5
11.	Test information	8
12.	Package outline	9
	Soldering	
	Revision history	
	Legal information	
	-	

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